National Semiconductor

T-67-21-51

MM54HC153/MM74HC153 Dual 4-Input Multiplexer

General Description

This 4-to-1 line multiplexer utilizes advanced silicon-gate CMOS technology. It has the low power consumption and high noise immunity of standard CMOS integrated circuits. This device is fully buffered, allowing it to drive 10 LS-TTL loads. Information on the data inputs of each multiplexer is selected by the address on the A and B inputs, and is presented on the Y outputs. Each multiplexer possesses a strobe input which enables it when taken to a low logic level. When a high logic level is applied to a strobe input, the output of its associated multiplexer is taken low.

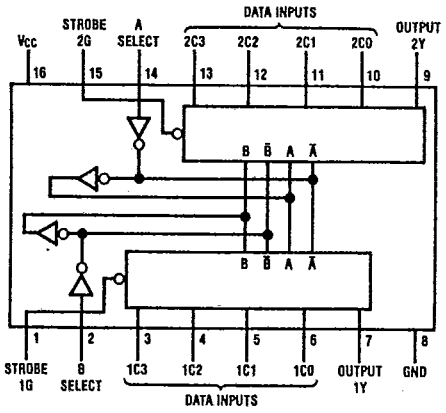
The 54HC/74HC logic family is functionally and pinout compatible with the standard 54LS/74LS logic family. All inputs are protected from damage due to static discharge by internal diode clamps to V_{CC} and ground.

Features

- Typical propagation delay: 24 ns
- Wide power supply range: 2V–6V
- Low quiescent current: 80 μA maximum (74HC Series)
- Low input current: 1 μA maximum
- Fanout of 10 LS-TTL loads

Connection Diagram

Dual-In-Line Package



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Top View

Order Number MM54HC153* or MM74HC153*

*Please look into Section 8, Appendix D for availability of various package types.

Truth Table

Select Inputs		Data Inputs				Strobe	Output
B	A	C0	C1	C2	C3	G	Y
X	X	X	X	X	X	H	L
L	L	L	X	X	X	L	L
L	L	H	X	X	X	L	H
L	H	X	L	X	X	L	L
L	H	X	H	X	X	L	H
H	L	X	X	L	X	L	L
H	L	X	X	H	X	L	H
H	H	X	X	X	L	L	L
H	H	X	X	X	H	L	H

Select inputs A and B are common to both sections.

H = high level, L = low level, X = don't care.

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Absolute Maximum Ratings (Notes 1 & 2)

If Military/Aerospace specified devices are required, contact the National Semiconductor Sales Office/ Distributors for availability and specifications.

Supply Voltage (V_{CC})	−0.5 to +7.0V
DC Input Voltage (V_{IN})	−1.5 to V_{CC}+1.5V
DC Output Voltage (V_{OUT})	−0.5 to V_{CC}+0.5V
Clamp Diode Current (I_{IK}, I_{OK})	±20 mA
DC Output Current, per pin (I_{OUT})	±25 mA
DC V_{CC} or GND Current, per pin (I_{CC})	±50 mA
Storage Temperature Range (T_{STG})	−65°C to +150°C
Power Dissipation (P_D) (Note 3)	600 mW
S.O. Package only	500 mW
Lead Temperature (T_L) (Soldering 10 seconds)	260°C

Operating Conditions

	Min	Max	Units
Supply Voltage (V_{CC})	2	6	V
DC Input or Output Voltage (V_{IN}, V_{OUT})	0	V_{CC}	V
Operating Temp. Range (T_A)			
MM74HC	−40	+85	°C
MM54HC	−55	+125	°C
Input Rise or Fall Times (t_r, t_f) V_{CC}=2.0V		1000	ns
V_{CC}=4.5V		500	ns
V_{CC}=6.0V		400	ns

DC Electrical Characteristics (Note 4)

Symbol	Parameter	Conditions	V_{CC}	T_A=25°C	74HC T_A=−40 to 85°C	54HC T_A=−55 to 125°C	Units
				Typ	Guaranteed Limits		
V_{IH}	Minimum High Level Input Voltage		2.0V		1.5	1.5	1.5	V
			4.5V		3.15	3.15	3.15	V
			6.0V		4.2	4.2	4.2	V
V_{IL}	Maximum Low Level Input Voltage**		2.0V		0.5	0.5	0.5	V
			4.5V		1.35	1.35	1.35	V
			6.0V		1.8	1.8	1.8	V
V_{OH}	Minimum High Level Output Voltage	V_{IN}=V_{IH} or V_{IL} $|I_{OUT}|\leq$20 μA	2.0V	2.0	1.9	1.9	1.9	V
			4.5V	4.5	4.4	4.4	4.4	V
			6.0V	6.0	5.9	5.9	5.9	V
		V_{IN}=V_{IH} or V_{IL} $|I_{OUT}|\leq$4.0 mA	4.5V	4.2	3.98	3.84	3.7	V
		$|I_{OUT}|\leq$5.2 mA	6.0V	5.3	5.48	5.34	5.2	V
V_{OL}	Maximum Low Level Output Voltage	V_{IN}=V_{IH} or V_{IL} $|I_{OUT}|\leq$20 μA	2.0V	0	0.1	0.1	0.1	V
			4.5V	0	0.1	0.1	0.1	V
			6.0V	0	0.1	0.1	0.1	V
		V_{IN}=V_{IH} or V_{IL} $|I_{OUT}|\leq$4.0 mA	4.5V	0.2	0.26	0.33	0.4	V
		$|I_{OUT}|\leq$5.2 mA	6.0V	0.2	0.26	0.33	0.4	V
I_{IN}	Maximum Input Current	V_{IN}=V_{CC} or GND	6.0V		±0.1	±1.0	±1.0	μA
I_{CC}	Maximum Quiescent Supply Current	V_{IN}=V_{CC} or GND I_{OUT}=0 μA	6.0V		8.0	80	160	μA

Note 1: Absolute Maximum Ratings are those values beyond which damage to the device may occur.

Note 2: Unless otherwise specified all voltages are referenced to ground.

Note 3: Power Dissipation temperature derating — plastic "N" package: −12 mW/°C from 65°C to 85°C; ceramic "J" package: −12 mW/°C from 100°C to 125°C.

Note 4: For a power supply of 5V ±10% the worst case output voltages (V_{OH}, and V_{OL}) occur for HC at 4.5V. Thus the 4.5V values should be used when designing with this supply. Worst case V_{IH} and V_{IL} occur at V_{CC}=5.5V and 4.5V respectively. (The V_{IH} value at 5.5V is 3.85V.) The worst case leakage current (I_{IN}, I_{CC}, and I_{OZ}) occur for CMOS at the higher voltage and so the 6.0V values should be used.

**V_{IL} limits are currently tested at 20% of V_{CC}. The above V_{IL} specification (30% of V_{CC}) will be implemented no later than Q1, CY'89.

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AC Electrical Characteristics $V_{CC}=5V$, $T_A=25°C$, $C_L=15$ pF, $t_r=t_f=6$ ns

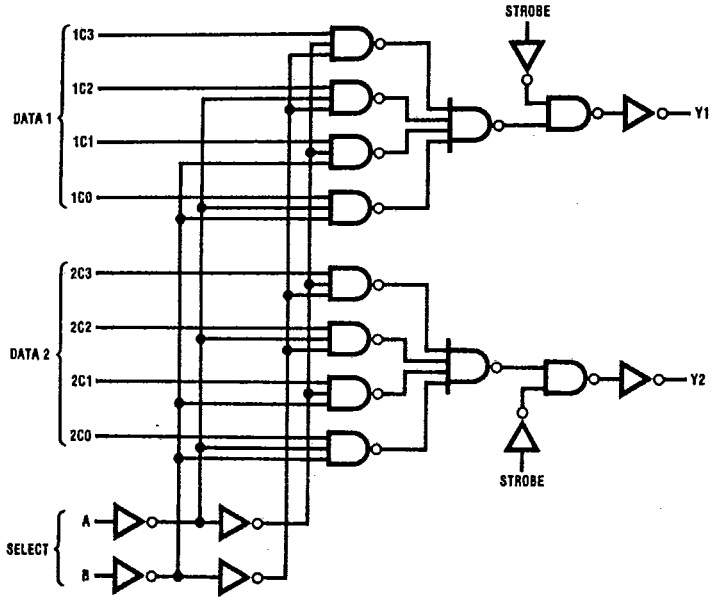
Symbol	Parameter	Conditions	Typ	Guaranteed Limit	Units
t_{PHL}, t_{PLH}	Maximum Propagation Delay, Select A or B to Y		26	30	ns
t_{PHL}, t_{PLH}	Maximum Propagation Delay, any Data to Y		20	23	ns
t_{PHL}, t_{PLH}	Maximum Propagation Delay, Strobe to Y		8	15	ns

AC Electrical Characteristics $C_L=50$ pF, $t_r=t_f=6$ ns (unless otherwise specified)

Symbol	Parameter	Conditions	V_{CC}	$T_A=25°C$	74HC $T_A=-40$ to $85°C$	54HC $T_A=-55$ to $125°C$	Units
				Typ	Guaranteed Limits		
t_{PHL}, t_{PLH}	Maximum Propagation Delay, Select A or B to Y		2.0V	131	158	198	237	ns
			4.5V	29	35	44	52	ns
			6.0V	25	30	38	45	ns
t_{PHL}, t_{PLH}	Maximum Propagation Delay, any Data to Y		2.0V	99	126	158	189	ns
			4.5V	22	28	35	42	ns
			6.0V	19	23	29	35	ns
t_{PHL}, t_{PLH}	Maximum Propagation Delay, Strobe to Y		2.0V	50	86	108	129	ns
			4.5V	12	19	24	29	ns
			6.0V	10	16	20	24	ns
t_{TLH}, t_{THL}	Maximum Output Rise and Fall Time		2.0V	30	75	95	110	ns
			4.5V	8	15	19	22	ns
			6.0V	7	13	16	19	ns
C_{IN}	Maximum Input Capacitance			5	10	10	10	pF
C_{PD}	Power Dissipation Capacitance	(Note 5)(per package) Outputs Enabled		90				pF
		Outputs Disabled		25				pF

Note 5: C_{PD} determines the no load dynamic power consumption, $P_D=C_{PD}\,V_{CC}^2\,f+I_{CC}\,V_{CC}$, and the no load dynamic current consumption, $I_S=C_{PD}\,V_{CC}\,f+I_{CC}$.

Logic Diagram



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